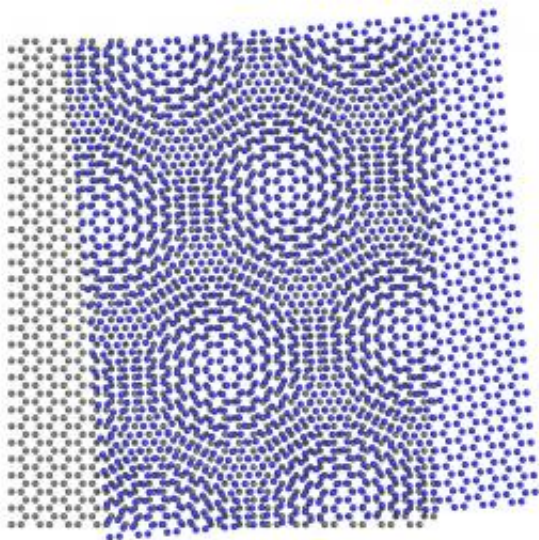


Seeing Moire in Graphene

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Moiré patterns appear when two or more periodic grids are overlaid slightly askew, which creates a new larger periodic pattern. Researchers from NIST and Georgia Tech imaged and interpreted the moiré patterns created by overlaid sheets of graphene to determine how the lattices of the individual sheets were stacked in relation to one another and to find subtle strains in the regions of bulges or wrinkles in the sheets. Credit: NIST

(PhysOrg.com) -- Researchers at the National Institute of Standards and Technology and the Georgia Institute of Technology have demonstrated that atomic scale moiré patterns, an interference pattern that appears when two or more grids are overlaid slightly askew, can be used to measure how sheets of graphene are stacked and reveal areas of strain.

The ability to determine the rotational orientation of graphene sheets and map strain is useful for understanding the electronic and transport properties of multiple layers of graphene, a one-atom thick form of carbon with potentially revolutionary semiconducting properties.

In digital photography, moiré (pronounced mwar-ray) patterns occur because of errors in the rendering process, which causes grid patterns to look wavy or distorted. Materials scientists have been using microscopic moiré patterns to detect stresses such as wrinkles or bulges in a variety of materials.

Researchers created graphene on the surface of a silicon carbide substrate at the Georgia Institute of Technology by heating one side so that only carbon, in the form of multilayer sheets of graphene, was left. Using a custom-built scanning tunneling microscope at NIST, the researchers were able to peer through the topmost layers of graphene to the layers beneath. This process, which the group dubbed “atomic moiré interferometry,” enabled them to image the patterns created by the stacked graphene layers, which in turn allowed the group to model how the hexagonal lattices of the individual graphene layers were stacked in relation to one another.

Unlike other materials that tend to stretch out when they cool, graphene bunches up like a wrinkled bed sheet. The researchers were able to map these stress fields by comparing the relative distortion of the hexagons of carbon atoms that comprise the individual graphene layers. Their technique is so sensitive that it is able to detect strains in the graphene layers causing as little as a 0.1 percent change in atom spacing.

This collaboration between NIST and the Georgia Institute of Technology is part of a series of experiments aimed at gaining a fundamental understanding of the properties of graphene.

Their article, “Structural analysis of multilayer [graphene](#) via atomic moiré interferometry” was selected as an Editor’s Highlight in *Physical Review B* for the month of March, 2010.

More information: D. Miller, K. Kubista, G. Rutter, M. Ruan, W. de Heer, P. First and J. Stroscio. Structural analysis of multilayer graphene via atomic moiré interferometry. *Physical Review B*. 81. 125427. Published March 24, 2010. prb.aps.org/abstract/PRB/v81/i12/e125427

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